PRIOR ART

FIG.21

LAYOUT DIAGRAM IN CASE PROCESS A DIRECTED TO FIG.20 IS APPLIED

VCC100

IH100

VSS100

IL100

IOL100

P1 P2 P3

N1 N2 N3

CONTENTS OF CONTACT

■ BETWEEN FIRST METAL LAYER AND SECOND METAL LAYER (Cv)

▨ BETWEEN FIRST METAL LAYER AND POLY-SILICON (Cp)

▨ BETWEEN FIRST METAL LAYER AND DEFFUSED LAYER

22
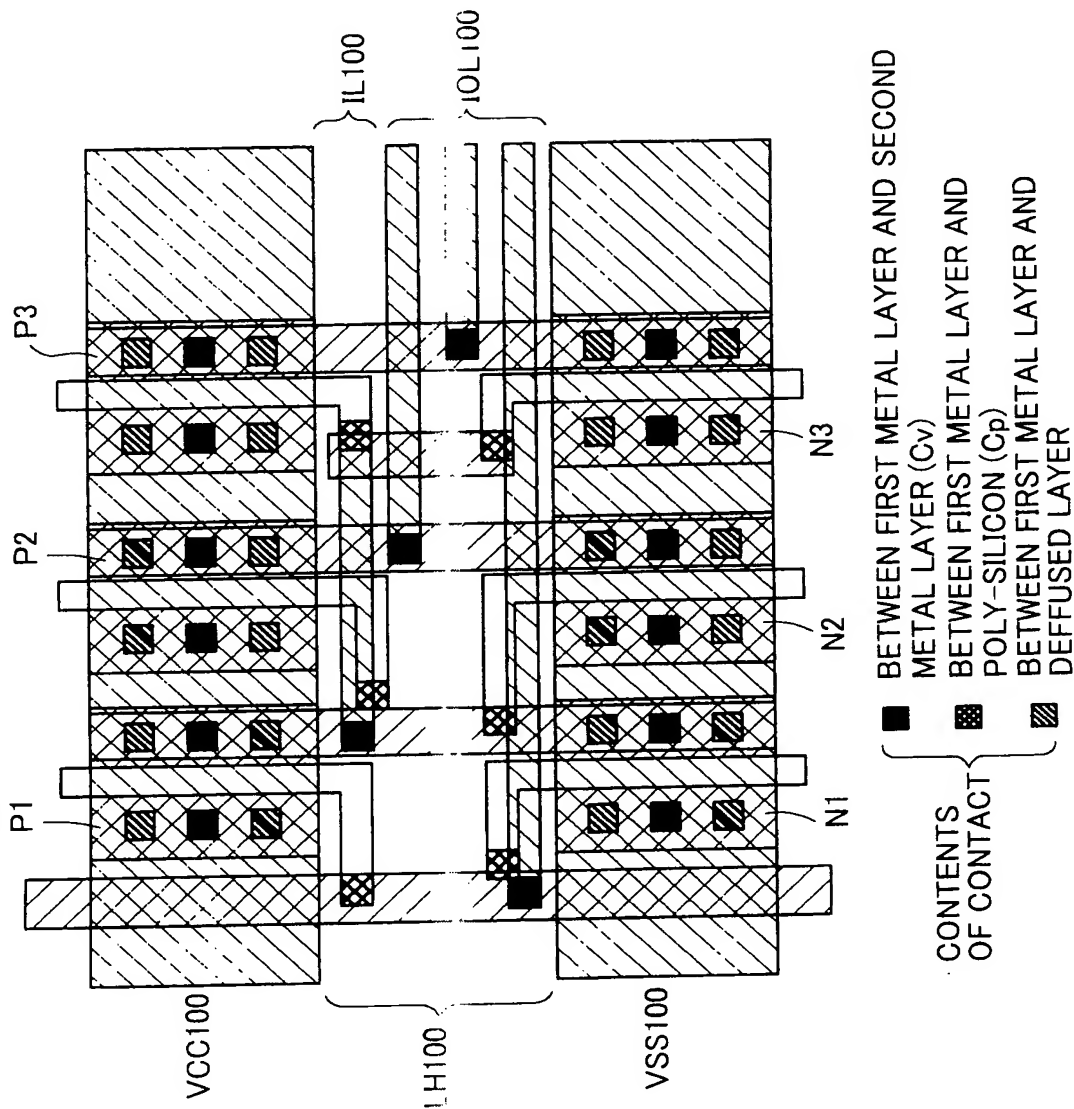
PRIOR ART

FIG.22

LAYOUT DIAGRAM IN CASE PROCESS B DIRECTED TO FIG.20 IS APPLIED